Third SPICE Exercise

Fundamentals Of Electronics - a.a. 2018-2019 - University of Padua (Italy)

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Chapter 1

Differential amplifier with MOS current source

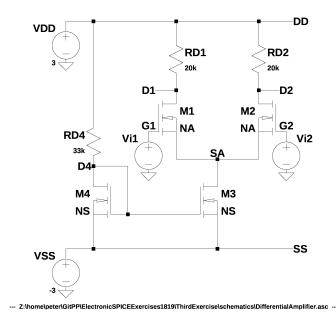


Figure 1.1: Differential amplifier with MOS current source

Initial data:

$$V_t = 0.5V \tag{1.1}$$

$$V_t = 0.5V$$

$$K'_n = \mu_n C_{ox} = 200 \frac{\mu A}{V^2}$$

$$\lambda = 0$$
(1.1)
$$(1.2)$$

$$\lambda = 0 \tag{1.3}$$

$$\left(\frac{W}{L}\right)_1 = \left(\frac{W}{L}\right)_2 = 20\tag{1.4}$$

$$\left(\frac{W}{L}\right)_3 = \left(\frac{W}{L}\right)_4 = 5\tag{1.5}$$

$$R_{D_1} = R_{D_2} = 20k\Omega (1.6)$$

$$R_{D_4} = \frac{30}{1000} \cdot 1097752\Omega = 32.93k\Omega \simeq 33k\Omega \tag{1.7}$$

$$V_{DD} = 3V (1.8)$$

$$V_{SS} = -3V \tag{1.9}$$

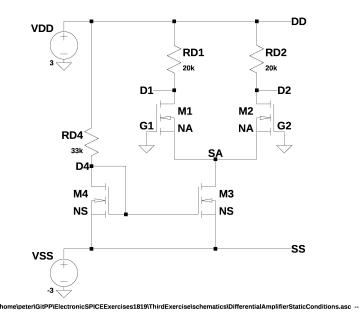


Figure 1.2: Differential amplifier with MOS current source - Static conditions

1.1 Static conditions - Analytic solution

On static conditions it's considered the input signals V_{i_1} and V_{i_2} turned off. The equivalent circuit is on figure 1.2.

1.1.1 MOSFET M_4

Saturation mode checks

The transistor M_4 has a short circuit between its drain and its gate, so the transistor works in saturation mode and the voltage between the drain and the gate are the same of the voltage between the gate and the source:

$$V_{D_4SS} > V_{G_4SS} - V_t \xrightarrow{V_{G_4SS} = V_{D_4SS}} V_{D_4SS} > V_{D_4SS} - V_t$$
 (1.10)

$$0 > -V_t$$
 (Always true: $V_t > 0$) (1.11)

It's requested to pay attention to the another check to confirm the work on saturation mode:

$$V_{G_4SS} > V_t \xrightarrow{V_{G_4SS} = V_{D_4SS}} V_{D_4SS} > V_t$$
 (1.12)

 $V_{D_4SS} \quad (=V_{G_4SS})$

Supposing that the transistor M_4 works on the saturation mode (see the section 1.1.1 for details), the current I_{D_4} could be calculated as:

$$I_{D_4} = \frac{1}{2} K'_n \left(\frac{W}{L}\right)_4 (V_{D_4SS} - V_t)^2$$
(1.13)

Other expression of the current I_{D_4} could be calculated using the LKT:

$$V_{DD} - R_{D_4} I_{D_4} - V_{D4SS} - V_{SS} = 0 \implies I_{D_4} = \frac{V_{DD} - V_{D_4SS} - V_{SS}}{R_{D_4}}$$
(1.14)

Using the equations 1.13 and 1.14 it's possible calculating V_{D_4SS} :

$$\frac{1}{2}K'_n\left(\frac{W}{L}\right)_4(V_{D_4SS} - V_t)^2 = \frac{V_{DD} - V_{D_4SS} - V_{SS}}{R_{D_4}}$$
(1.15)

$$\frac{1}{2} \cdot 200 \frac{\mu A}{V^2} \cdot 5 \frac{\mu m}{\mu m} (V_{D_4 SS} - 0.5V)^2 = \frac{3V - V_{D_4 SS} - (-3V)}{33k\Omega}$$
(1.16)

$$500\frac{\mu A}{V^2}(V_{D_4SS} - 0.5V)^2 = \frac{6}{33}mA - \frac{1}{33k\Omega}V_{D_4SS}$$
 (1.17)

$$500\frac{\mu A}{V^2}(V_{D_4SS}^2 - V_{D_4SS} \cdot V + 0.25V^2) = \frac{6}{33}mA - \frac{1}{33k\Omega}V_{D_4SS}$$
 (1.18)

$$500\frac{\mu A}{V^2} \cdot V_{D_4SS}^2 + \left(-500\frac{\mu A}{V^2}V + \frac{1}{33k\Omega}\right)V_{D_4SS} + 500\frac{\mu A}{V^2} \cdot 0.25V^2 - \frac{6}{33}mA = 0 \tag{1.19}$$

$$0.5\frac{mA}{V^2} \cdot V_{D_4SS}^2 + \left(-0.5\frac{mA}{V^2}V + \frac{1}{33k\Omega}\right)V_{D_4SS} + 0.5\frac{mA}{V^2} \cdot 0.25V^2 - \frac{6}{33}mA = 0$$
 (1.20)

$$\left(0.5 \frac{mA}{V^2}\right) V_{D_4SS}^2 + \left(-\frac{31}{66} \frac{mA}{V}\right) V_{D_4SS} + \left(-\frac{5}{88} mA\right) = 0 \tag{1.21}$$

$$V_{D_4SS_{1,2}} = \frac{-\left(-\frac{31}{66}\frac{mA}{V}\right) \pm \sqrt{\left(-\frac{31}{66}\frac{mA}{V}\right)^2 - 4 \cdot \left(0.5\frac{mA}{V^2}\right) \cdot \left(-\frac{5}{88}mA\right)}}{2 \cdot 0.5\frac{mA}{V^2}} = \begin{cases} 1.04784V \\ -0.10845V \text{ Not possible: } < \text{ of } V_t \end{cases}$$

$$(1.22)$$

Now it's possible to check the last equation that can confirm the work on saturation mode of the MOSFET M_4 (equation 1.12):

$$1.04784V > 0.5V$$
 M_4 works on saturation mode. (1.23)

 I_{D_4}

Using the equation 1.13 and the result of the equation 1.22:

$$I_{D_4} = \frac{1}{2} \cdot 200\mu A/V^2 \cdot 5\frac{\mu m}{\mu m} \cdot (1.04784V - 0.5V)^2 = 150.06433\mu A \tag{1.24}$$

1.1.2 MOSFET M_3

 V_{G_3SS}

Observing the circuit represented on the figure 1.2 it's clear that the voltage V_{G_3SS} is equal to the voltage V_{D_4SS} calculated in the equation 1.22.

$$V_{G_3SS} = V_{D_4SS} (1.25)$$

 I_{S_A}

As agree with the consideration of the section 1.1.2 and supposing the work of the MOSFET M_3 on the saturation mode, it's possible calculating the drain current of the MOSFET M_3 :

$$I_{SA} = \frac{1}{2} K'_n \left(\frac{W}{L}\right)_3 (V_{D_4SS} - V_t)^2$$
(1.26)

$$I_{SA} = \frac{1}{2} \cdot 200\mu A/V^2 \cdot 5\frac{\mu m}{\mu m} \cdot (1.04784V - 0.5V)^2 = 150.06433\mu A \tag{1.27}$$

Saturation mode checks

For obtaining the confirm of the work of the MOSFET M_3 on saturation mode the next two equations have to be satisfied:

$$V_{D_3SS} > V_{G_3SS} - V_t \xrightarrow{V_{D_3SS} = V_{S_ASS}, V_{G_3SS} = V_{D_4SS}} V_{S_ASS} > V_{D_4SS} - V_t$$
(1.28)

$$V_{G_3SS} > V_t \xrightarrow{V_{G_3SS} = V_{D_4SS}} V_{D_4SS} > V_t$$
 (1.29)

The equation 1.28 hasn't to be checked, V_{S_ASS} isn't calculated yet.

The equation 1.29 is satisfied (see the equation 1.23).

1.1.3 MOSFET M_1 and MOSFET M_2

The MOSFET M_1 and the MOSFET M_2 have the same dimension and the same constructive parameters (see initial data at the start of this chapter 1).

They also have the same voltage applied to every their pins (see figure 1.2).

So, additionally supposing the work on the saturation mode of M_1 and M_2 , it's possible to confirm the next equations:

$$I_{D_1} = I_{D_2} \tag{1.30}$$

$$V_{G_1S_A} = V_{G_2S_A} (1.31)$$

$$V_{D_1S_A} = V_{D_2S_A} (1.32)$$

 $I_{D_1} (= I_{D_2})$

LKC node
$$S_A$$
: $I_{D_1} + I_{D_2} - I_{S_A} = 0 \xrightarrow{eq.1.30} 2I_{D_1} - I_{S_A} = 0 \implies I_{D_1} = \frac{I_{S_A}}{2}$ (1.33)

$$I_{D_1} = \frac{150.06433\mu A}{2} = 75.03217\mu A \tag{1.34}$$

 $V_{G_1S_A}(=V_{G_2S_A})$

Supposing the work of the MOSFET M_1 (equally M_2) on the saturation mode, the drain current could be calculated as:

$$I_{D_1} = \frac{1}{2} K_n' \left(\frac{W}{L}\right)_1 (V_{G_1 S_A} - V_t)^2 \tag{1.35}$$

It's possible using the equation 1.35 to calculate $V_{G_1S_A}$:

$$I_{D_1} = \frac{1}{2} K_n' \left(\frac{W}{L}\right)_1 (V_{G_1 S_A} - V_t)^2$$
(1.36)

$$\sqrt{I_{D_1}} = \sqrt{\frac{1}{2}K_n'\left(\frac{W}{L}\right)_1}(V_{G_1S_A} - V_t)$$
(1.37)

$$\sqrt{\frac{I_{D_1}}{\frac{1}{2}K'_n\left(\frac{W}{I_L}\right)_1}} = V_{G_1S_A} - V_t \tag{1.38}$$

$$V_{G_1S_A} = \sqrt{\frac{2I_{D_1}}{K_n'\left(\frac{W}{L}\right)_1}} + V_t \tag{1.39}$$

$$V_{G_1S_A} = \sqrt{\frac{2 \cdot 75.03217\mu A}{200\mu A \cdot 20\frac{\mu A}{\mu A}}} + 0.5V \tag{1.40}$$

$$V_{G_1S_A} = 0.69369V (1.41)$$

 V_{S_A} Now it's possible calculating the voltage on the node S_A :

$$V_{G_1S_A} = V_{G_1} - V_{S_A} \implies V_{S_A} = V_{G_1} - V_{G_1S_A} \xrightarrow{V_{G_1} = 0, eq. 1.41} V_{S_A} = -0.69369V$$
 (1.42)

Saturation mode checks

In order to check the mode of the M_1 (and M_2) the equations to respect are 1.43 and 1.48.

$$V_{D_1S_A} > V_{G_1S_A} - Vt (1.43)$$

$$V_{D_1} - V_{S_A} > V_{G_1S_A} - Vt (1.44)$$

$$I_{D_1}R_{D_1} - V_{S_A} > V_{G_1S_A} - Vt (1.45)$$

$$75.03217\mu A \cdot 20k\Omega - (-0.69369V) > 0.69369V - 0.5V \tag{1.46}$$

$$2.19433V > 0.19369V$$
 True. (1.47)

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$$V_{G_1S_A} > V_t \tag{1.48}$$

$$0.69369V > 0.5V$$
 True. (1.49)

Checking the mode of the M3's work (see equation 1.28):

$$V_{S_ASS} > V_{D_4SS} - V_t \tag{1.50}$$

$$V_{S_A} - V_{SS} > V_{D_4SS} - V_t (1.51)$$

$$-0.69369V - (-3V) > 1.04784V - 0.5V \tag{1.52}$$

$$2.30631V > 0.54784V \quad M_3 \text{ works on the saturation mode.}$$
 (1.53)

1.1.4 MOSFET V_{DS_Q} , V_{GS_Q} , I_{D_Q} - Resuming

MOSFET	V_{DS_Q}	V_{GS_Q}	I_{D_Q}
M1	$V_{D_1S_A} = 2.19433V$	$V_{G_1S_A} = 0.69369V$	$I_{D_1} = 75.03217\mu A$
M2	$V_{D_2S_A} = 2.19433V$	$V_{G_2S_A} = 0.69369V$	$I_{D_2} = 75.03217 \mu A$
M3	$V_{S_ASS} = 2.30631V$	$V_{D_4SS} = 1.04784V$	$I_{S_A} = 150.06433 \mu A$
M4	$V_{D_4SS} = 1.04784V$	$V_{D_4SS} = 1.04784V$	$I_{D_4} = 150.06433\mu A$

1.2 SPICE analysis

1.2.1 Operating Point on static conditions

```
* Differential Amplifier - Static conditions
*********************************
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* Commons, PO Box 1866, Mountain View, CA 94042, USA.
***********************************
* Parameters
. param RD = 20k
* NMOS models
. model NA NMOS VT0=0.5 KP=200u LAMBDA=0 W=4.00u L=0.20u
. model NS NMOS VT0=0.5 KP=200u LAMBDA=0 W=1.25u L=0.25u
* Resistances
RD1 DD D1 {RD}
RD2 DD D2 {RD}
RD4 DD D4 33k
* Transistors
M1 D1 G1 SA SA NA
M2 D2 G2 SA SA NA
M3 SA D4 SS SS NS
M4 D4 D4 SS SS NS
* Voltage sources
VDD DD 0 3
VSS SS 0 -3
Vi1 G1 0 0
Vi2 G2 0 0
* Analysis
.op
```

.END

```
Operating Point ---
V(dd):
                             voltage
V(d1):
           1.49935
                             voltage
V(d2):
           1.49935
                             voltage
V(d4):
           -1.95216
                             voltage
V(g1):
           0
                             voltage
V(sa):
           -0.693691
                             voltage
V(g2):
           0
                             voltage
V(ss):
           -3
                             voltage
Id (M4):
           0.000150065
                             device_current
Ig (M4):
                             device_current
Ib (M4):
           -1.05784e-012
                             device_current
Is (M4):
           -0.000150065
                             device_current
Id (M3):
           0.000150065
                             device_current
Ig (M3):
                             device_current
Ib (M3):
           -2.31631e-012
                             device_current
Is (M3):
           -0.000150065
                             device_current
Id (M2):
           7.50327e - 005
                             device_current
Ig (M2):
           0
                             device_current
Ib (M2):
           -2.20304e-012
                             device_current
Is (M2):
           -7.50327e-005
                             device_current
Id (M1):
           7.50327e-005
                             device_current
Ig (M1):
                             device_current
Ib (M1):
           -2.20304e-012
                             device_current
Is (M1):
           -7.50327e-005
                             device_current
I (Rd4):
           0.000150065
                             device_current
I(Rd2):
           7.50327e - 005
                             device_current
I (Rd1):
           7.50327e - 005
                             device_current
I (Vi2):
                             device_current
I (Vi1):
           0
                             device_current
I (Vss):
           0.000300131
                             device_current
I (Vdd):
                             device_current
           -0.000300131
```

1.2.2 Operating Point - common mode signal

```
* Differential Amplifier - Common Mode signals
*************************
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* Commons, PO Box 1866, Mountain View, CA 94042, USA.
********************
* Parameters
. param RD = 20k
* NMOS models
. model NA NMOS VT0=0.5 KP=200u LAMBDA=0 W=4.00u L=0.20u
. model NS NMOS VT0=0.5 KP=200u LAMBDA=0 W=1.25u L=0.25u
* Resistances
RD1 DD D1 {RD}
RD2 DD D2 {RD}
```

1.2. SPICE ANALYSIS

```
* Transistors
MI DI GI SA SA NA
M2 D2 G2 SA SA NA
M3 SA D4 SS SS NS
M4 D4 D4 SS SS NS

* Voltage sources
VDD DD 0 3
VSS SS 0 -3
Vi1 G1 0 sine(0 10m 10k 0 0 0)
Vi2 G2 0 sine(0 10m 10k 0 0 0)

* Analysis
.op
.END
```

```
Operating Point ----
V(dd):
           3
                              voltage
V(d1):
           1.49935
                              voltage
V(d2):
           1.49935
                              voltage
V(d4):
           -1.95216
                              voltage
V(g1):
           0
                              voltage
V(sa):
           -0.693691
                              voltage
V(g2):
           0
                              voltage
V(ss):
           -3
                              voltage
Id (M4):
           0.000150065
                              device_current
Ig (M4):
                              device_current
Ib (M4):
           -1.05784e-012
                              device_current
Is (M4):
           -0.000150065
                              device_current
Id (M3):
           0.000150065
                              device_current
Ig (M3):
           0
                              device_current
Ib (M3):
           -2.31631e-012
                              device_current
Is (M3):
           -0.000150065
                              device_current
Id (M2):
           7.50327e - 005
                              device_current
Ig (M2):
           0
                              device_current
Ib (M2):
           -2.20304e-012
                              device_current
Is (M2):
           -7.50327e-005
                              device_current
Id (M1):
           7.50327\,\mathrm{e}\!-\!005
                              device_current
Ig (M1):
                              device_current
Ib (M1):
           -2.20304e-012
                              device_current
Is (M1):
           -7.50327e-005
                              device_current
I (Rd4):
           0.000150065
                              device_current
I (Rd2):
           7.50327e - 005
                              device_current
I (Rd1):
           7.50327e - 005
                              device_current
                              device_current
I(Vi2):
           0
I (Vi1):
           0
                              device_current
I (Vss):
           0.000300131
                              device_current
I(Vdd):
           -0.000300131
                              device_current
```

1.2.3 Operating Point - differential signals

```
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* Commons, PO Box 1866, Mountain View, CA 94042, USA.
**********************************
* Parameters
.param RD = 20k
* NMOS models
. model NA NMOS VT0=0.5 KP=200u LAMBDA=0 W=4.00u L=0.20u
. model NS NMOS VT0=0.5 KP=200u LAMBDA=0 W=1.25u L=0.25u
* Resistances
RD1 DD D1 {RD}
RD2 DD D2 {RD}
RD4 DD D4 33k
* Transistors
M1 D1 G1 SA SA NA
M2 D2 G2 SA SA NA
M3 SA D4 SS SS NS
M4 D4 D4 SS SS NS
* Voltage sources
VDD DD 0 3
VSS SS 0 -3
Vi1 G1 0 sine (0 10m 10k 0 0 0)
Vi2 G2 0 0
* Analysis
.op
.END
```

```
Operating Point -
V(dd):
           3
                               voltage
V(d1):
            1.49935
                               voltage
V(d2):
            1.49935
                               voltage
V(d4):
            -1.95216
                               voltage
V(g1):
           0
                               voltage
V(sa):
            -0.693691
                               voltage
V(g2):
           0
                               voltage
V(ss):
           -3
                               voltage
Id (M4):
            0.000150065
                               device_current
Ig (M4):
                               device_current
Ib (M4):
            -1.05784\,\mathrm{e}\!-\!012
                               device\_current
Is (M4):
            -0.000150065
                               device_current
Id (M3):
            0.000150065
                               device_current
Ig (M3):
                               device_current
Ib (M3):
            -2.31631e-012
                               device_current
Is (M3):
            -0.000150065
                               device_current
Id (M2):
            7.50327e - 005
                               device_current
                               d\,e\,v\,i\,c\,e\,{}_{-}\,c\,u\,r\,r\,e\,n\,t
Ig (M2):
           0
Ib (M2):
            -2.20304e-012
                               device_current
Is (M2):
            -7.50327e-005
                               device_current
Id (M1):
           7.50327e - 005
                               device_current
Ig (M1):
                               device\_current
           0
Ib (M1):
            -2.20304e-012
                               device_current
```

1.2. SPICE ANALYSIS

```
Is (M1):
             -7.50327e-005
                                  device_current
I (Rd4):
             0.000150065
                                  {\tt device\_current}
I (Rd2):
             7.50327\,\mathrm{e}\!-\!005
                                  device\_current
I (Rd1):
             7.50327\,\mathrm{e}\!-\!005
                                  device\_current
I (Vi2):
             0
                                  {\tt device\_current}
I (Vi1):
             0
                                  {\tt device\_current}
             0.000300131
I(Vss):
                                  {\tt device\_current}
I(Vdd):
             -0.000300131
                                  \tt device\_current
```